



High Voltage Fast-Switching NPN Power Transistor

TO-251 (IPAK) TO-252 (DPAK)



Pin Definition: 1. Base 2. Collector

3. Emitter

PRODUCT SUMMARY

BV _{CEO}	450V
BV _{CBO}	1050V
I _C	4A
V _{CE(SAT)}	0.5V @ I _C =1A, I _B =0.2A

Features

- High Voltage Capability
- High Switching Speed

Structure

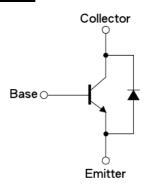
- Silicon Triple Diffused Type
- NPN Silicon Transistor

Ordering Information

Part No.	Package	Packing
TSC5804DCH C5G	TO-251	75pcs / Tube
TSC5804DCP ROG	TO-252	2.5Kpcs / 13" Reel

Note: "G" denote for Halogen Free Product

Block Diagram



Absolute Maximum Rating (T_A = 25°C, unless otherwise noted)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V_{CBO}	1050	V
Collector-Emitter Voltage @ V _{BE} =0V	V _{CES}	450	V
Emitter-Base Voltage	V_{EBO}	15	V
Collector Current	I _C	4	А
Collector Peak Current (tp <5ms)	I _{CM}	8	А
Base Current	I _B	2	А
Base Peak Current (tp <5ms)	I _{BM}	4	Α
Power Total Dissipation @ Tc=25°C	P _{DTOT}	45	W
Maximum Operating Junction Temperature	T _J	+150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

Note: Single Pulse. P_W = 300uS, Duty ≤2%

Thermal Performance

Parameter	Symbol	Limit	Unit	
Thermal Resistance – Junction to Case	R⊖ _{JC}	2.78	°C/W	
Thermal Resistance - Junction to Ambient	$R\Theta_{JA}$	100	°C/W	



Pb RoHS

TSC5804D

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Electrical Specifications (T_A = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static						
Collector-Base Voltage	I _C =0.5mA	BV _{CBO}	1050			V
Collector-Emitter Breakdown Voltage	I _C =5mA	BV _{CEO}	450			V
Emitter-Base Breakdown Voltage	I _E =1mA	BV _{EBO}	15			V
Collector Cutoff Current	$V_{CE} = 400 \text{V}, I_{B} = 0$	I _{CEO}		10	250	uA
Collector Cutoff Current	$V_{CB} = 950 \text{V}, I_{E} = 0$	I _{CBO}			10	uA
Collector-Emitter Saturation Voltage	I _C =1A, I _B =0.2A	V _{CE(SAT)} 1		1	0.5	V
Collector-Emitter Saturation Voltage	I _C =3.5A, I _B =1A	V _{CE(SAT)} 2		1.5	2.0	V
Base-Emitter Saturation Voltage	I _C =3.5A, I _B =1A	V _{BE(SAT)} 1		1.1	1.5	V
DC Current Gain	$V_{CE} = 5V$, $I_C = 100$ mA	h _{FE} 1	50	70	100	
	$V_{CE} = 3V, I_{C} = 800 \text{mA}$	h _{FE} 2	25	30	50	
Diode Forward Voltage	I _C =2A	V_{F}			1.5	V
Resistive Load Switching Time (Ratings)						
Rise Time		t _r		-	1	uS
Storage Time	$V_{CC} = 5V, I_C = 0.5A,$	t _{STG}	4.5	5	5.5	uS
Fall Time		t _f			1.2	uS

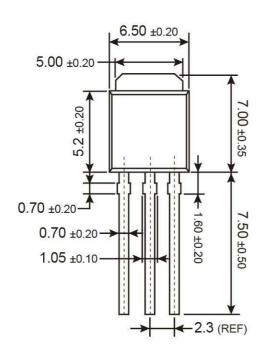
Notes: Pulsed duration =380uS, duty cycle ≤2%

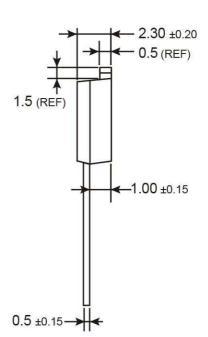


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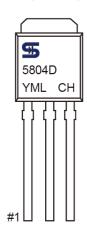
TO-251 Mechanical Drawing





Unit: Millimeters

Marking Diagram



Y = Year Code

M = Month Code for Halogen Free Product
(O=Jan, P=Feb, Q=Mar, R=Apl, S=May, T=Jun, U=Jul, V=Aug, W=Sep, X=Oct, Y=Nov, Z=Dec)

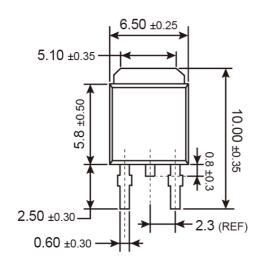
L = Lot Code

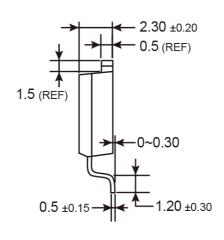




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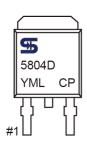
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